

74HC564

Octal D-type flip-flop; positive-edge trigger; 3-state; inverting

Rev. 03 — 11 November 2004

Product data sheet

1. General description

The 74HC564 is a high-speed Si-gate CMOS device and is pin compatible with low-power Schottky TTL (LSTTL). The 74HC564 is specified in compliance with JEDEC standard no. 7A.

The 74HC564 is a octal D-type flip-flop featuring separate D-type inputs for each flip-flop and inverting 3-state outputs for bus oriented applications. A clock (CP) and an output enable ($\overline{OE}$) input are common to all flip-flops.

The 8 flip-flops will store the state of their individual D-inputs that meet the set-up and hold times requirements on the LOW-to-HIGH CP transition. When $\overline{OE}$ is LOW, the contents of the 8 flip-flops are available at the outputs. When $\overline{OE}$ is HIGH, the outputs go to the high-impedance OFF-state. Operation of the $\overline{OE}$ input does not affect the state of the flip-flops.

The 74HC564 is functionally identical to the 74HC574 but has inverting outputs. The 74HC564 is functionally identical to the 74HC534, but has a different pinning.

2. Features

- 3-state inverting outputs for bus oriented applications
- 8-bit positive-edge triggered register
- Common 3-state output enable input
- Independent register and 3-state buffer operation
- Low-power dissipation
- Complies with JEDEC standard no. 7A
- ESD protection:
 - ◆ HBM EIA/JESD22-A114-B exceeds 2000 V
 - ◆ MM EIA/JESD22-A115-A exceeds 200 V.
- Multiple package options
- Specified from $-40\text{ }^{\circ}\text{C}$ to $+80\text{ }^{\circ}\text{C}$ and from $-40\text{ }^{\circ}\text{C}$ to $+125\text{ }^{\circ}\text{C}$.

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3. Quick reference data

Table 1: Quick reference data
 $GND = 0\text{ V}$; $T_{amb} = 25\text{ °C}$; $t_r = t_f = 6\text{ ns}$.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
t_{PHL} , t_{PLH}	propagation delay CP to $\bar{Q}$ n	$C_L = 15\text{ pF}$; $V_{CC} = 5\text{ V}$	-	15	-	ns
f_{max}	maximum clock frequency	$C_L = 15\text{ pF}$; $V_{CC} = 5\text{ V}$	-	127	-	MHz
C_i	input capacitance		-	3.5	-	pF
C_{PD}	power dissipation capacitance per flip-flop	$V_i = GND$ to V_{CC}	[1] -	27	-	pF

[1] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma(C_L \times V_{CC}^2 \times f_o)$ where:

f_i = input frequency in MHz;

f_o = output frequency in MHz;

C_L = output load capacitance in pF;

V_{CC} = supply voltage in V;

N = number of inputs switching;

$\Sigma(C_L \times V_{CC}^2 \times f_o)$ = sum of outputs.

4. Ordering information

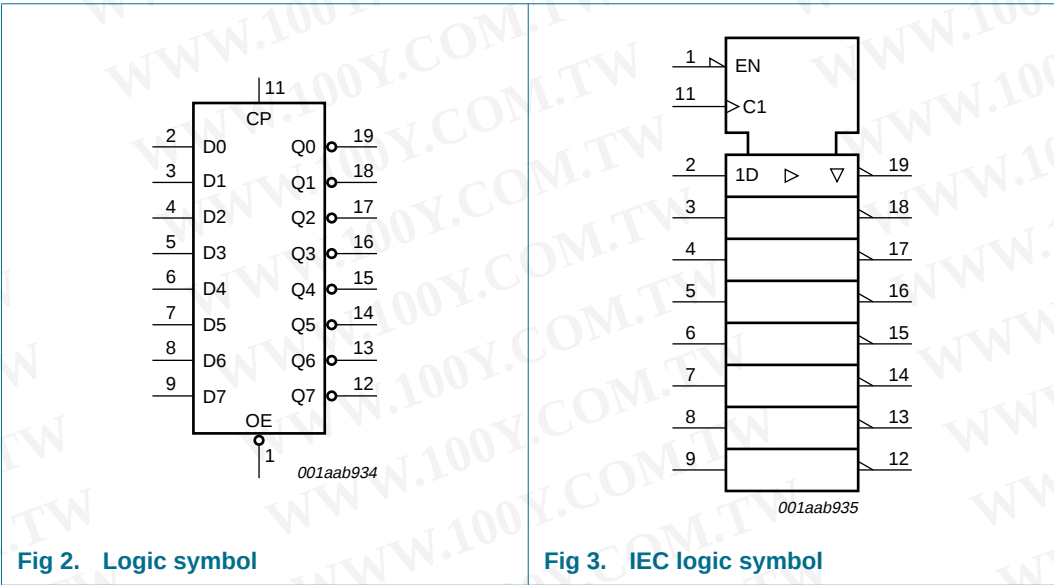
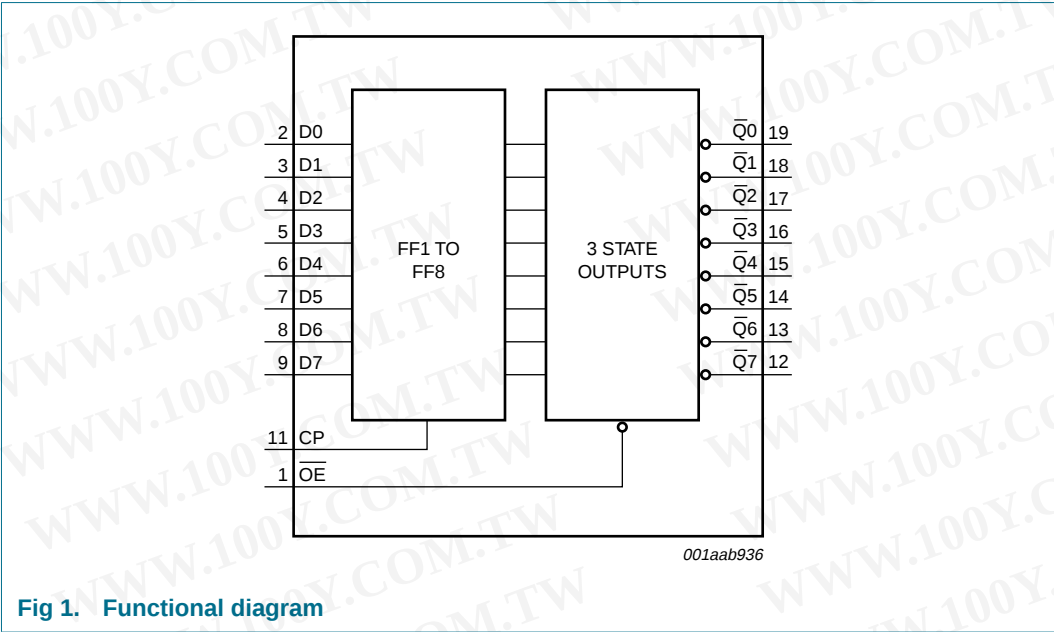
Table 2: Ordering information

Type number	Package			
	Temperature range	Name	Description	Version
74HC564N	-40 °C to +125 °C	DIP20	plastic dual in-line package; 20 leads (300 mil)	SOT146-1
74HC564D	-40 °C to +125 °C	SO20	plastic small outline package; 20 leads; body width 7.5 mm	SOT163-1

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5. Functional diagram



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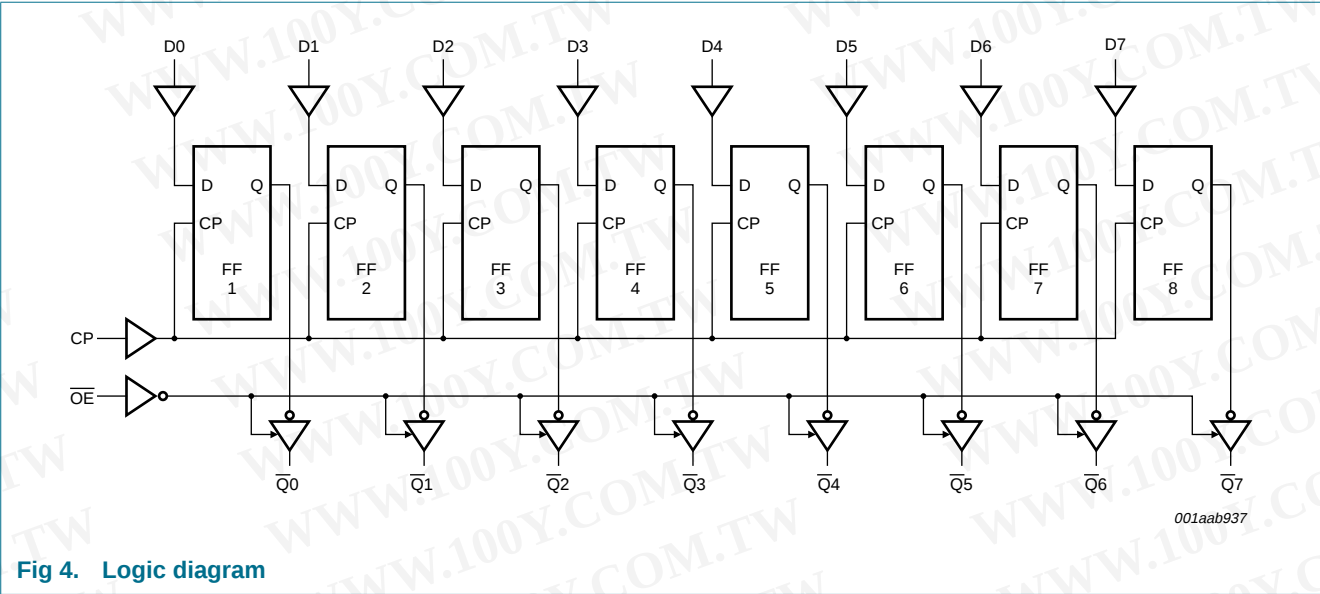


Fig 4. Logic diagram

6. Pinning information

6.1 Pinning

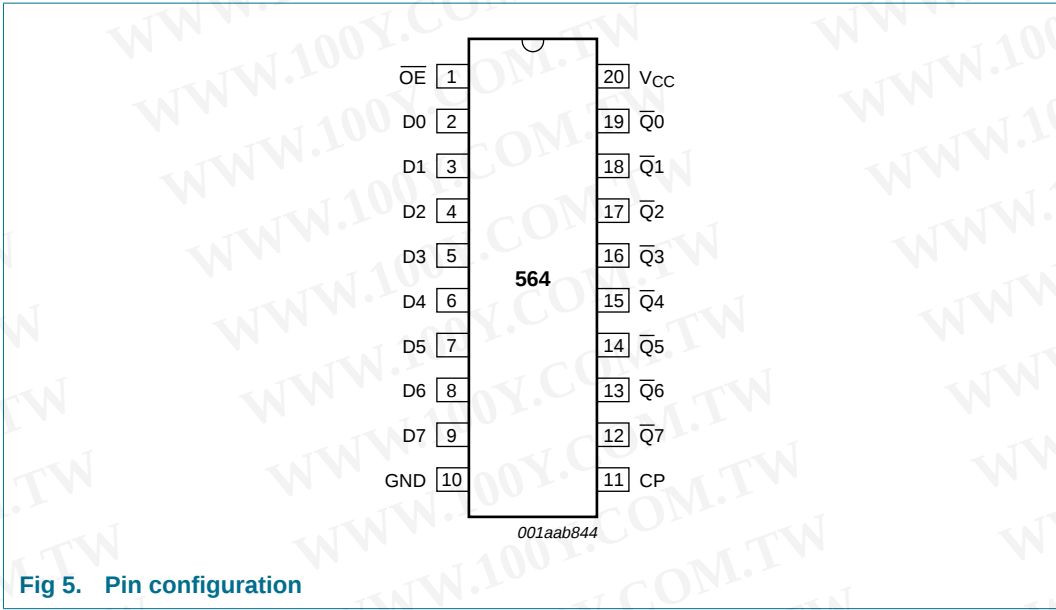


Fig 5. Pin configuration

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6.2 Pin description

Table 3: Pin description

Symbol	Pin	Description
$\overline{OE}$	1	3-state output enable input (active LOW)
D0	2	data input 0
D1	3	data input 1
D2	4	data input 2
D3	5	data input 3
D4	6	data input 4
D5	7	data input 5
D6	8	data input 6
D7	9	data input 7
GND	10	ground (0 V)
CP	11	clock input (LOW-to-HIGH, edge-triggered)
$\overline{Q}7$	12	3-state flip-flop output 7
$\overline{Q}6$	13	3-state flip-flop output 6
$\overline{Q}5$	14	3-state flip-flop output 5
$\overline{Q}4$	15	3-state flip-flop output 4
$\overline{Q}3$	16	3-state flip-flop output 3
$\overline{Q}2$	17	3-state flip-flop output 2
$\overline{Q}1$	18	3-state flip-flop output 1
$\overline{Q}0$	19	3-state flip-flop output 0
V _{CC}	20	positive supply voltage

7. Functional description

7.1 Function table

Table 4: Function table ^[1]

Operating mode	Input			Internal flip-flop	Output $\overline{Q}_n$
	$\overline{OE}$	CP	D _n		
Load and read register	L	↑	L	L	H
			h	H	L
Load register and disable output	H	↑	L	L	Z
			h	H	Z

- [1] H = HIGH voltage level;
 h = HIGH voltage level one set-up time prior to the LOW-to-HIGH CP transition;
 L = LOW voltage level;
 l = LOW voltage level one set-up time prior to the LOW-to-HIGH CP transition;
 Z = high-impedance OFF-state;
 ↑ = LOW-to-HIGH clock transition.

8. Limiting values

Table 5: Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	supply voltage		-0.5	+7	V
I_{IK}	input diode current	$V_I < -0.5 \text{ V}$ or $V_I > V_{CC} + 0.5 \text{ V}$	-	± 20	mA
I_{OK}	output diode current	$V_O < -0.5 \text{ V}$ or $V_O > V_{CC} + 0.5 \text{ V}$	-	± 20	mA
I_O	output source or sink current	$V_O = -0.5 \text{ V}$ to $V_{CC} + 0.5 \text{ V}$	-	± 35	mA
I_{CC}, I_{GND}	V_{CC} or GND current		-	± 70	mA
T_{stg}	storage temperature		-65	+150	°C
P_{tot}	power dissipation				
	DIP20 package		[1]	-	750 mW
	SO20 package		[2]	-	500 mW

[1] Above 70 °C: P_{tot} derates linearly with 12 mW/K.

[2] Above 70 °C: P_{tot} derates linearly with 8 mW/K.

9. Recommended operating conditions

Table 6: Recommended operating conditions

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_{CC}	supply voltage		2.0	5.0	6.0	V
V_I	input voltage		0	-	V_{CC}	V
V_O	output voltage		0	-	V_{CC}	V
t_r, t_f	input rise and fall times	$V_{CC} = 2.0 \text{ V}$	-	-	1000	ns
		$V_{CC} = 4.5 \text{ V}$	-	6.0	500	ns
		$V_{CC} = 6.0 \text{ V}$	-	-	400	ns
T_{amb}	ambient temperature		-40	-	+125	°C

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10. Static characteristics

Table 7: Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
T_{amb} = 25 °C						
V _{IH}	HIGH-level input voltage	V _{CC} = 2.0 V	1.5	1.2	-	V
		V _{CC} = 4.5 V	3.15	2.4	-	V
		V _{CC} = 6.0 V	4.2	3.2	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 2.0 V	-	0.8	0.5	V
		V _{CC} = 4.5 V	-	2.1	1.35	V
		V _{CC} = 6.0 V	-	2.8	1.8	V
V _{OH}	HIGH-level output voltage	V _I = V _{IH} or V _{IL}				
		I _O = -20 µA; V _{CC} = 2.0 V	1.9	2.0	-	V
		I _O = -20 µA; V _{CC} = 4.5 V	4.4	4.5	-	V
		I _O = -20 µA; V _{CC} = 6.0 V	5.9	6.0	-	V
		I _O = -6.0 mA; V _{CC} = 4.5 V	3.98	4.32	-	V
		I _O = -7.8 mA; V _{CC} = 6.0 V	5.48	5.81	-	V
V _{OL}	LOW-level output voltage	V _I = V _{IH} or V _{IL}				
		I _O = 20 µA; V _{CC} = 2.0 V	-	0	0.1	V
		I _O = 20 µA; V _{CC} = 4.5 V	-	0	0.1	V
		I _O = 20 µA; V _{CC} = 6.0 V	-	0	0.1	V
		I _O = 6.0 mA; V _{CC} = 4.5 V	-	0.15	0.26	V
		I _O = 7.8 mA; V _{CC} = 6.0 V	-	0.16	0.26	V
I _{LI}	input leakage current	V _I = V _{CC} or GND; V _{CC} = 6.0 V	-	-	±0.1	µA
I _{OZ}	3-state OFF-state current	V _I = V _{IH} or V _{IL} ; V _{CC} = 6.0 V; V _O = V _{CC} or GND	-	-	±0.5	µA
I _{CC}	quiescent supply current	V _I = V _{CC} or GND; I _O = 0 A; V _{CC} = 6.0 V	-	-	8.0	µA
C _I	input capacitance		-	3.5	-	pF
T_{amb} = -40 °C to +85 °C						
V _{IH}	HIGH-level input voltage	V _{CC} = 2.0 V	1.5	-	-	V
		V _{CC} = 4.5 V	3.15	-	-	V
		V _{CC} = 6.0 V	4.2	-	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 2.0 V	-	-	0.5	V
		V _{CC} = 4.5 V	-	-	1.35	V
		V _{CC} = 6.0 V	-	-	1.8	V
V _{OH}	HIGH-level output voltage	V _I = V _{IH} or V _{IL}				
		I _O = -20 µA; V _{CC} = 2.0 V	1.9	-	-	V
		I _O = -20 µA; V _{CC} = 4.5 V	4.4	-	-	V
		I _O = -20 µA; V _{CC} = 6.0 V	5.9	-	-	V
		I _O = -6.0 mA; V _{CC} = 4.5 V	3.84	-	-	V
		I _O = -7.8 mA; V _{CC} = 6.0 V	5.34	-	-	V

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Table 7: Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_{OL}	LOW-level output voltage	$V_I = V_{IH}$ or V_{IL}				
		$I_O = 20\ \mu\text{A}$; $V_{CC} = 2.0\ \text{V}$	-	-	0.1	V
		$I_O = 20\ \mu\text{A}$; $V_{CC} = 4.5\ \text{V}$	-	-	0.1	V
		$I_O = 20\ \mu\text{A}$; $V_{CC} = 6.0\ \text{V}$	-	-	0.1	V
		$I_O = 6.0\ \text{mA}$; $V_{CC} = 4.5\ \text{V}$	-	-	0.33	V
		$I_O = 7.8\ \text{mA}$; $V_{CC} = 6.0\ \text{V}$	-	-	0.33	V
I_{LI}	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 6.0\ \text{V}$	-	-	± 1.0	μA
I_{OZ}	3-state OFF-state current	$V_I = V_{IH}$ or V_{IL} ; $V_{CC} = 6.0\ \text{V}$; $V_O = V_{CC}$ or GND	-	-	± 5.0	μA
I_{CC}	quiescent supply current	$V_I = V_{CC}$ or GND; $I_O = 0\ \text{A}$; $V_{CC} = 6.0\ \text{V}$	-	-	80	μA
$T_{amb} = -40\ ^\circ\text{C}$ to $+125\ ^\circ\text{C}$						
V_{IH}	HIGH-level input voltage	$V_{CC} = 2.0\ \text{V}$	1.5	-	-	V
		$V_{CC} = 4.5\ \text{V}$	3.15	-	-	V
		$V_{CC} = 6.0\ \text{V}$	4.2	-	-	V
V_{IL}	LOW-level input voltage	$V_{CC} = 2.0\ \text{V}$	-	-	0.5	V
		$V_{CC} = 4.5\ \text{V}$	-	-	1.35	V
		$V_{CC} = 6.0\ \text{V}$	-	-	1.8	V
V_{OH}	HIGH-level output voltage	$V_I = V_{IH}$ or V_{IL}		-		
		$I_O = -20\ \mu\text{A}$; $V_{CC} = 2.0\ \text{V}$	1.9	-	-	V
		$I_O = -20\ \mu\text{A}$; $V_{CC} = 4.5\ \text{V}$	4.4	-	-	V
		$I_O = -20\ \mu\text{A}$; $V_{CC} = 6.0\ \text{V}$	5.9	-	-	V
		$I_O = -6.0\ \text{mA}$; $V_{CC} = 4.5\ \text{V}$	3.7	-	-	V
		$I_O = -7.8\ \text{mA}$; $V_{CC} = 6.0\ \text{V}$	5.2	-	-	V
V_{OL}	LOW-level output voltage	$V_I = V_{IH}$ or V_{IL}		-		
		$I_O = 20\ \mu\text{A}$; $V_{CC} = 2.0\ \text{V}$	-	-	0.1	V
		$I_O = 20\ \mu\text{A}$; $V_{CC} = 4.5\ \text{V}$	-	-	0.1	V
		$I_O = 20\ \mu\text{A}$; $V_{CC} = 6.0\ \text{V}$	-	-	0.1	V
		$I_O = 6.0\ \text{mA}$; $V_{CC} = 4.5\ \text{V}$	-	-	0.4	V
		$I_O = 7.8\ \text{mA}$; $V_{CC} = 6.0\ \text{V}$	-	-	0.4	V
I_{LI}	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 6.0\ \text{V}$	-	-	± 1.0	μA
I_{OZ}	3-state OFF-state current	$V_I = V_{IH}$ or V_{IL} ; $V_{CC} = 6.0\ \text{V}$; $V_O = V_{CC}$ or GND	-	-	± 10.0	μA
I_{CC}	quiescent supply current	$V_I = V_{CC}$ or GND; $I_O = 0\ \text{A}$; $V_{CC} = 6.0\ \text{V}$	-	-	160	μA

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11. Dynamic characteristics

Table 8: Dynamic characteristics

$GND = 0\text{ V}$; $t_r = t_f = 6\text{ ns}$; $C_L = 50\text{ pF}$; see [Figure 9](#).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$T_{amb} = 25\text{ }^{\circ}\text{C}$						
t_{PHL}, t_{PLH}	propagation delay CP to $\overline{Qn}$	see Figure 6				
		$V_{CC} = 2.0\text{ V}$	-	50	165	ns
		$V_{CC} = 4.5\text{ V}$	-	18	33	ns
		$V_{CC} = 6.0\text{ V}$	-	14	28	ns
		$V_{CC} = 5.0\text{ V}$; $C_L = 15\text{ pF}$	-	15	-	ns
t_{PZH}, t_{PZL}	3-state output enable time $\overline{OE}$ to $\overline{Qn}$	see Figure 7				
		$V_{CC} = 2.0\text{ V}$	-	44	140	ns
		$V_{CC} = 4.5\text{ V}$	-	16	28	ns
		$V_{CC} = 6.0\text{ V}$	-	13	24	ns
t_{PHZ}, t_{PLZ}	3-state output disable time $\overline{OE}$ to $\overline{Qn}$	see Figure 7				
		$V_{CC} = 2.0\text{ V}$	-	50	135	ns
		$V_{CC} = 4.5\text{ V}$	-	18	27	ns
		$V_{CC} = 6.0\text{ V}$	-	14	23	ns
t_{THL}, t_{TLH}	output transition time	see Figure 6				
		$V_{CC} = 2.0\text{ V}$	-	14	60	ns
		$V_{CC} = 4.5\text{ V}$	-	5	12	ns
		$V_{CC} = 6.0\text{ V}$	-	4	10	ns
t_w	CP clock pulse width HIGH or LOW	see Figure 6				
		$V_{CC} = 2.0\text{ V}$	80	14	-	ns
		$V_{CC} = 4.5\text{ V}$	16	5	-	ns
		$V_{CC} = 6.0\text{ V}$	14	4	-	ns
t_{su}	set-up time Dn to CP	see Figure 8				
		$V_{CC} = 2.0\text{ V}$	60	6	-	ns
		$V_{CC} = 4.5\text{ V}$	12	2	-	ns
		$V_{CC} = 6.0\text{ V}$	10	2	-	ns
t_h	hold time Dn to CP	see Figure 8				
		$V_{CC} = 2.0\text{ V}$	5	0	-	ns
		$V_{CC} = 4.5\text{ V}$	5	0	-	ns
		$V_{CC} = 6.0\text{ V}$	5	0	-	ns
f_{max}	maximum clock frequency	see Figure 6				
		$V_{CC} = 2.0\text{ V}$	6.0	38	-	MHz
		$V_{CC} = 4.5\text{ V}$	30	115	-	MHz
		$V_{CC} = 6.0\text{ V}$	35	137	-	MHz
		$V_{CC} = 5.0\text{ V}$; $C_L = 15\text{ pF}$	-	127	-	MHz
C_{PD}	power dissipation capacitance per flip-flop	$V_I = GND$ to V_{CC}	1	27	-	pF

Table 8: Dynamic characteristics ...continued
 $GND = 0\text{ V}$; $t_r = t_f = 6\text{ ns}$; $C_L = 50\text{ pF}$; see [Figure 9](#).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$T_{\text{amb}} = -40\text{ °C to }+85\text{ °C}$						
$t_{\text{PHL}}, t_{\text{PLH}}$	propagation delay CP to $\overline{Qn}$	see Figure 6				
		$V_{\text{CC}} = 2.0\text{ V}$	-	-	205	ns
		$V_{\text{CC}} = 4.5\text{ V}$	-	-	41	ns
		$V_{\text{CC}} = 6.0\text{ V}$	-	-	35	ns
$t_{\text{PZH}}, t_{\text{PZL}}$	3-state output enable time $\overline{OE}$ to $\overline{Qn}$	see Figure 7				
		$V_{\text{CC}} = 2.0\text{ V}$	-	-	175	ns
		$V_{\text{CC}} = 4.5\text{ V}$	-	-	35	ns
		$V_{\text{CC}} = 6.0\text{ V}$	-	-	30	ns
$t_{\text{PHZ}}, t_{\text{PLZ}}$	3-state output disable time $\overline{OE}$ to $\overline{Qn}$	see Figure 7				
		$V_{\text{CC}} = 2.0\text{ V}$	-	-	170	ns
		$V_{\text{CC}} = 4.5\text{ V}$	-	-	34	ns
		$V_{\text{CC}} = 6.0\text{ V}$	-	-	29	ns
$t_{\text{THL}}, t_{\text{TLH}}$	output transition time	see Figure 6				
		$V_{\text{CC}} = 2.0\text{ V}$	-	-	75	ns
		$V_{\text{CC}} = 4.5\text{ V}$	-	-	15	ns
		$V_{\text{CC}} = 6.0\text{ V}$	-	-	13	ns
t_w	CP clock pulse width HIGH or LOW	see Figure 6				
		$V_{\text{CC}} = 2.0\text{ V}$	100	-	-	ns
		$V_{\text{CC}} = 4.5\text{ V}$	20	-	-	ns
		$V_{\text{CC}} = 6.0\text{ V}$	17	-	-	ns
t_{su}	set-up time Dn to CP	see Figure 8				
		$V_{\text{CC}} = 2.0\text{ V}$	75	-	-	ns
		$V_{\text{CC}} = 4.5\text{ V}$	15	-	-	ns
		$V_{\text{CC}} = 6.0\text{ V}$	13	-	-	ns
t_h	hold time Dn to CP	see Figure 8				
		$V_{\text{CC}} = 2.0\text{ V}$	5	-	-	ns
		$V_{\text{CC}} = 4.5\text{ V}$	5	-	-	ns
		$V_{\text{CC}} = 6.0\text{ V}$	5	-	-	ns
f_{max}	maximum clock frequency	see Figure 6				
		$V_{\text{CC}} = 2.0\text{ V}$	4.8	-	-	MHz
		$V_{\text{CC}} = 4.5\text{ V}$	24	-	-	MHz
		$V_{\text{CC}} = 6.0\text{ V}$	28	-	-	MHz

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Table 8: Dynamic characteristics ...continued
 $GND = 0\text{ V}$; $t_r = t_f = 6\text{ ns}$; $C_L = 50\text{ pF}$; see [Figure 9](#).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$T_{\text{amb}} = -40\text{ }^{\circ}\text{C to } +125\text{ }^{\circ}\text{C}$						
$t_{\text{PHL}}, t_{\text{PLH}}$	propagation delay CP to $\overline{\text{Qn}}$	see Figure 6				
		$V_{\text{CC}} = 2.0\text{ V}$	-	-	250	ns
		$V_{\text{CC}} = 4.5\text{ V}$	-	-	50	ns
		$V_{\text{CC}} = 6.0\text{ V}$	-	-	43	ns
$t_{\text{PZH}}, t_{\text{PZL}}$	3-state output enable time $\overline{\text{OE}}$ to $\overline{\text{Qn}}$	see Figure 7				
		$V_{\text{CC}} = 2.0\text{ V}$	-	-	210	ns
		$V_{\text{CC}} = 4.5\text{ V}$	-	-	42	ns
		$V_{\text{CC}} = 6.0\text{ V}$	-	-	36	ns
$t_{\text{PHZ}}, t_{\text{PLZ}}$	3-state output disable time $\overline{\text{OE}}$ to $\overline{\text{Qn}}$	see Figure 7				
		$V_{\text{CC}} = 2.0\text{ V}$	-	-	205	ns
		$V_{\text{CC}} = 4.5\text{ V}$	-	-	41	ns
		$V_{\text{CC}} = 6.0\text{ V}$	-	-	35	ns
$t_{\text{THL}}, t_{\text{TLH}}$	output transition time	see Figure 6				
		$V_{\text{CC}} = 2.0\text{ V}$	-	-	90	ns
		$V_{\text{CC}} = 4.5\text{ V}$	-	-	18	ns
		$V_{\text{CC}} = 6.0\text{ V}$	-	-	15	ns
t_{w}	CP clock pulse width HIGH or LOW	see Figure 6				
		$V_{\text{CC}} = 2.0\text{ V}$	120	-	-	ns
		$V_{\text{CC}} = 4.5\text{ V}$	24	-	-	ns
		$V_{\text{CC}} = 6.0\text{ V}$	20	-	-	ns
t_{su}	set-up time Dn to CP	see Figure 8				
		$V_{\text{CC}} = 2.0\text{ V}$	90	-	-	ns
		$V_{\text{CC}} = 4.5\text{ V}$	18	-	-	ns
		$V_{\text{CC}} = 6.0\text{ V}$	15	-	-	ns
t_{h}	hold time Dn to CP	see Figure 8				
		$V_{\text{CC}} = 2.0\text{ V}$	5	-	-	ns
		$V_{\text{CC}} = 4.5\text{ V}$	5	-	-	ns
		$V_{\text{CC}} = 6.0\text{ V}$	5	-	-	ns
f_{max}	maximum clock frequency	see Figure 6				
		$V_{\text{CC}} = 2.0\text{ V}$	4.0	-	-	MHz
		$V_{\text{CC}} = 4.5\text{ V}$	20	-	-	MHz
		$V_{\text{CC}} = 6.0\text{ V}$	24	-	-	MHz

[1] C_{PD} is used to determine the dynamic power dissipation (P_{D} in μW).

$P_{\text{D}} = C_{\text{PD}} \times V_{\text{CC}}^2 \times f_i \times N + \sum (C_L \times V_{\text{CC}}^2 \times f_o)$ where:

f_i = input frequency in MHz;

f_o = output frequency in MHz;

C_L = output load capacitance in pF;

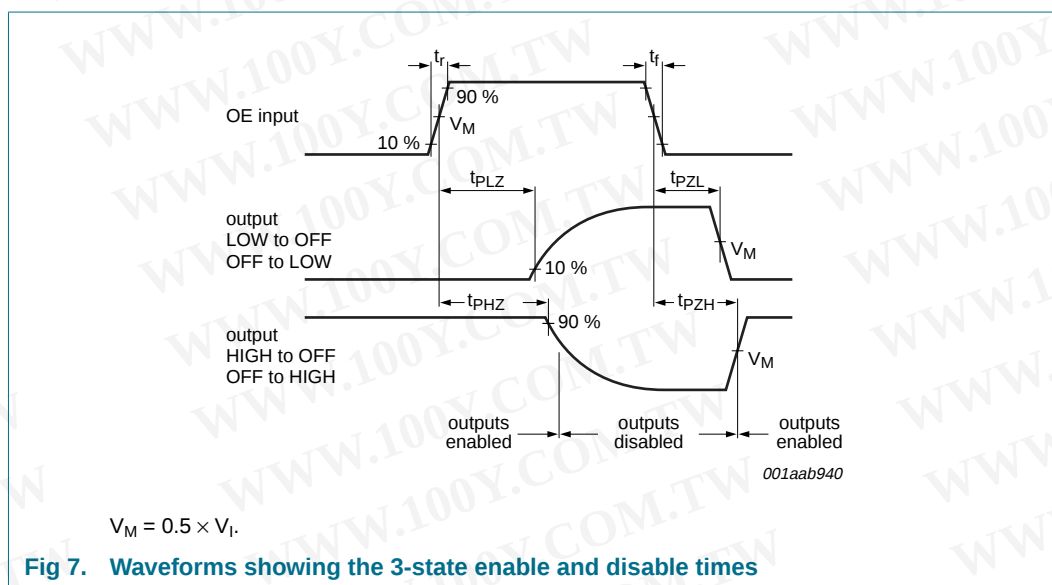
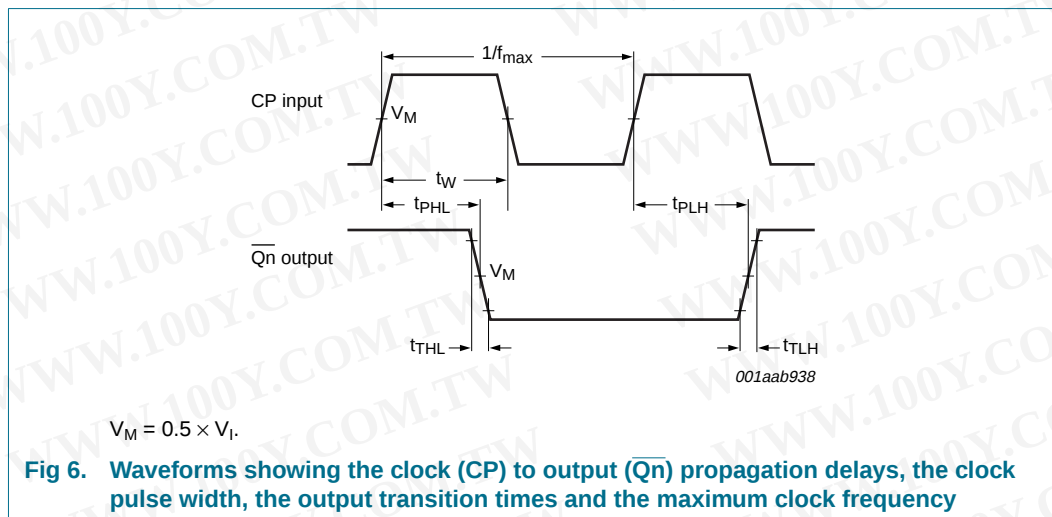
V_{CC} = supply voltage in V;

N = number of inputs switching;

$\sum (C_L \times V_{\text{CC}}^2 \times f_o)$ = sum of outputs.

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12. Waveforms



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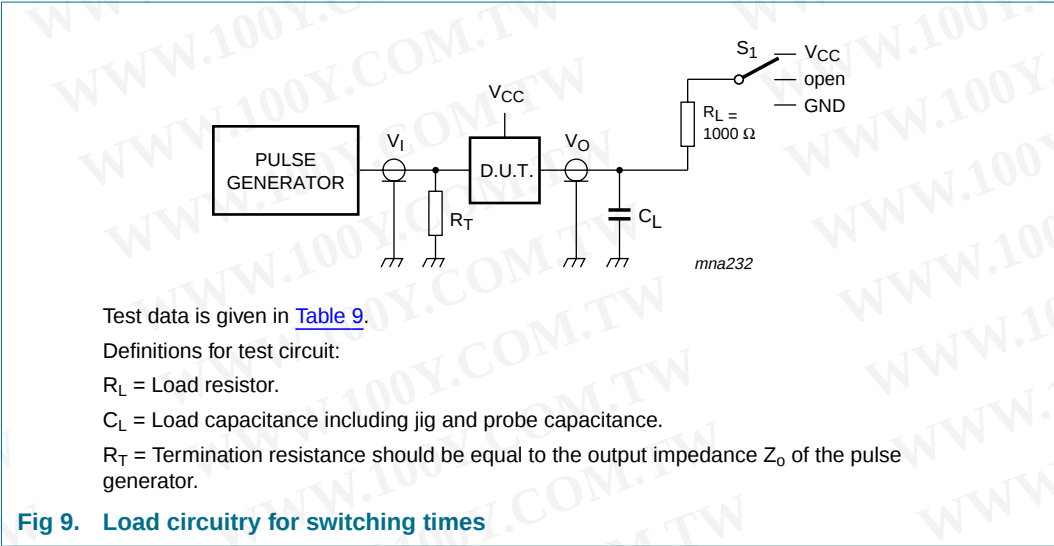
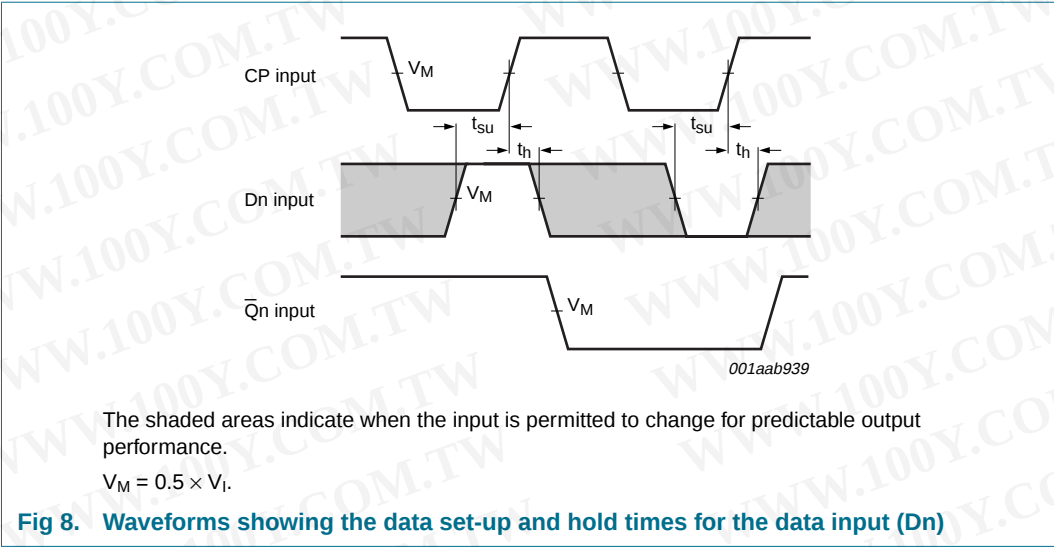


Table 9: Test data							
Supply	Input		Load		S1		
VCC	VI	tr = tr	CL	RL	tpZL, tPLZ	tpZH, tPHZ	tpHL, tPLH
2.0 V	VCC	6 ns	50 pF	1 kΩ	VCC	GND	open
4.5 V	VCC	6 ns	50 pF	1 kΩ	VCC	GND	open
6.0 V	VCC	6 ns	50 pF	1 kΩ	VCC	GND	open
5.0 V	VCC	6 ns	15 pF	1 kΩ	VCC	GND	open

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13. Package outline

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DIP20: plastic dual in-line package; 20 leads (300 mil)

SOT146-1

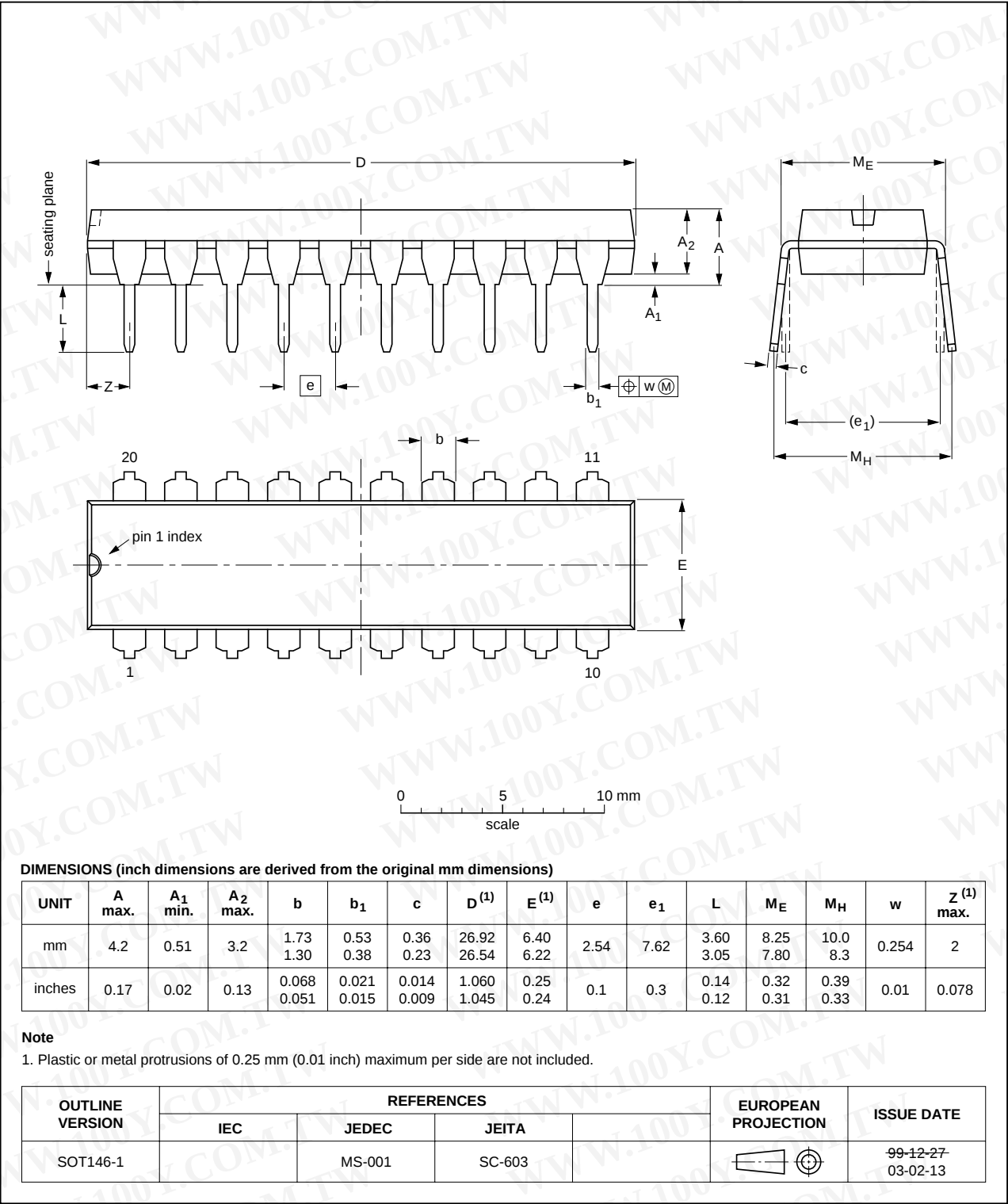


Fig 10. Package outline SOT146-1 (DIP20)

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SO20: plastic small outline package; 20 leads; body width 7.5 mm

SOT163-1

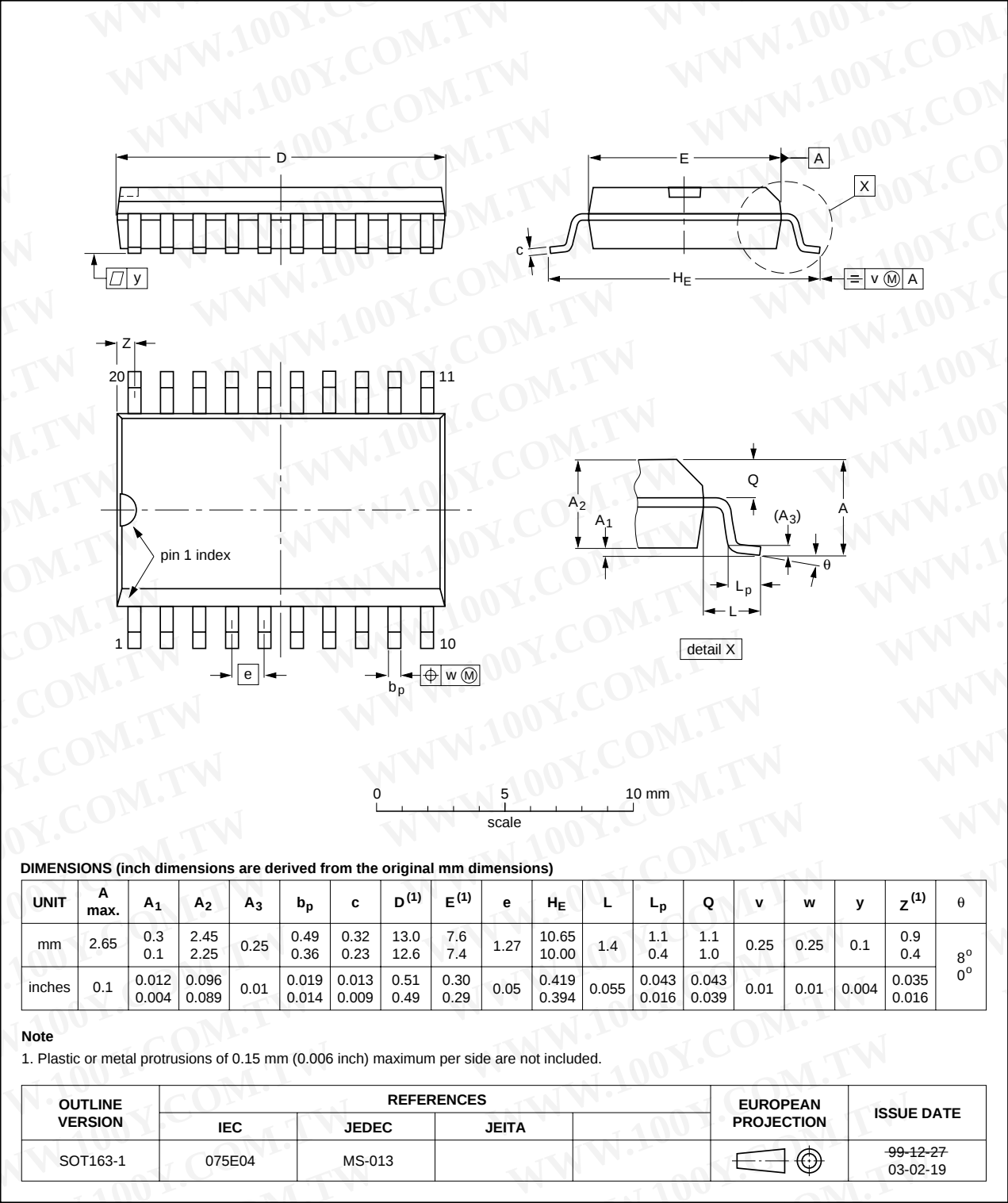


Fig 11. Package outline SOT163-1 (SO20)

14. Revision history

Table 10: Revision history

Document ID	Release date	Data sheet status	Change notice	Doc. number	Supersedes
74HC564_3	20041111	Product data sheet	-	9397 750 13814	74HC_HCT564_CNV_2
Modifications:					
- The format of this data sheet has been redesigned to comply with the current presentation and information standard of Philips Semiconductors. - Removed type number 74HCT564. - Inserted family specification.					
74HC_HCT564_CNV_2	19970905	Product specification	-	-	74HC_HCT564_1
74HC_HCT564_1	19901201	Product specification	-	-	-

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15. Data sheet status

Level	Data sheet status ^[1]	Product status ^{[2][3]}	Definition
I	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
II	Preliminary data	Qualification	This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product.
III	Product data	Production	This data sheet contains data from the product specification. Philips Semiconductors reserves the right to make changes at any time in order to improve the design, manufacturing and supply. Relevant changes will be communicated via a Customer Product/Process Change Notification (CPCN).

[1] Please consult the most recently issued data sheet before initiating or completing a design.

[2] The product status of the device(s) described in this data sheet may have changed since this data sheet was published. The latest information is available on the Internet at URL <http://www.semiconductors.philips.com>.

[3] For data sheets describing multiple type numbers, the highest-level product status determines the data sheet status.

16. Definitions

Short-form specification — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

Application information — Applications that are described herein for any of these products are for illustrative purposes only. Philips Semiconductors make no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

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18. Contact information

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For sales office addresses, send an email to: sales.addresses@www.semiconductors.philips.com

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